## NSN 5961-01-079-7818

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View Online at https://aerobasegroup.com/nsn/5961-01-079-7818 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 20.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** 200 nanoseconds maximum reverse recovery time **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0